

ASDL-5771

High Performance Photodiode in Side Look Package



Data Sheet

Description

ASDL-5771 is a Silicon PIN Photodiode encapsulated in dark green Side Look package. The added feature of a dark tint acts as an optical filter to reduce effects of ambient light from interfering with the Infrared signal. It is ideal for applications from 700nm to 1100nm that require high sensitivity over wide viewing angle at smaller outline dimension.

Features

- Dark Green Side Look Package
- High Sensitivity
- Low Dark Current
- Low Junction Capacitance
- Wide Viewing Angle
- Lead Free & ROHS Compliant
- Available in Tape & Reel

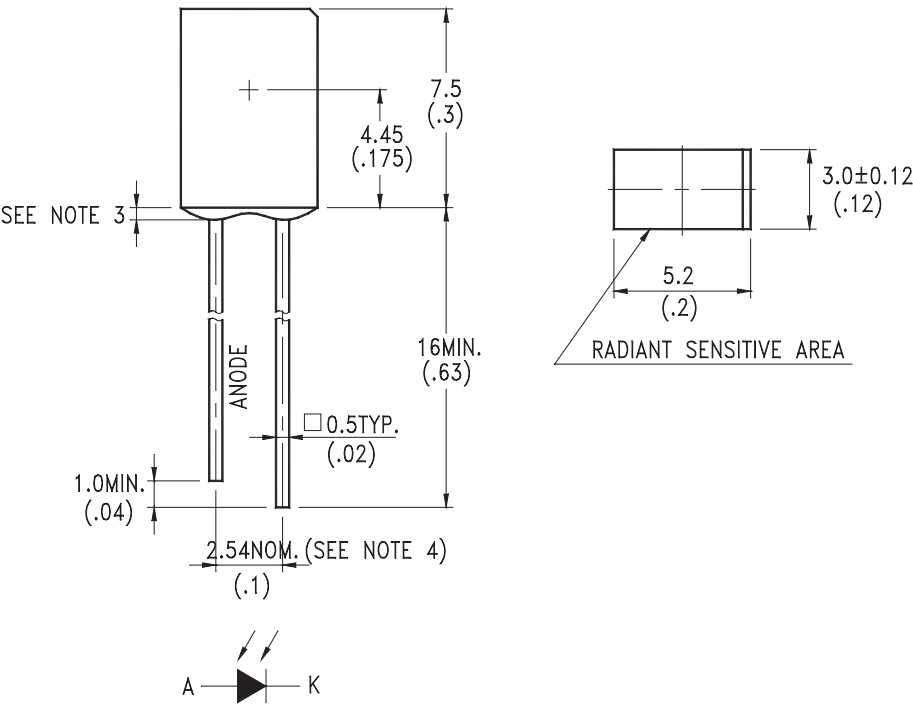
Applications

- Detector in Consumer Electronics
- Detector Industrial Electronics & Equipment

Ordering Information

Part Number	Lead Form	Color	Packaging	Shipping Option
ASDL-5771-D22	Straight	Dark Green	Tape & Reel	4000pcs
ASDL-5771-D31			Bulk	8000pcs / Carton

Package Dimensions



- Notes:
1. All dimensions are in millimeters (inches)
 2. Tolerance is + 0.25mm (.010") unless otherwise noted
 3. Lead spacing is measured where leads emerge from package
 4. Specifications are subject to change without notice.

Absolute Maximum Ratings at T_A=25°C

Parameter	Symbol	Min.	Max	Unit
Power Dissipation	P _{DISS}		150	mW
Reverse Voltage (I _r =100uA)	V _R		30	V
Operating Temperature	T _O	-40	85	°C
Storage Temperature	T _S	-55	100	°C
Junction temperature	T _J		110	°C
Lead Soldering Temperature [.6mm (0.063") From Body]		260°C for 5 seconds		

Electrical Characteristics at 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage	V _F		1	1.3	V	I _F = 50mA
Breakdown Voltage	V _{BR}	30			V	I _R = 100uA Ee = 0mW/cm ²
Reverse Dark Current	I _D			30	nA	V _R =10V Ee=0mW/cm ²
Diode Capacitance	C _O		25		pF	V _R = 3V F = 1MHZ Ee = 0mW/cm ²
Open Circuit Voltage	V _{OC}		350		mV	λ = 940nm Ee=0.5mW/cm ²
Thermal Resistance, Junction to Pin	Rθ _{JP}		375		°C/W	

Optical Characteristics at 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Photocurrent	I _{PH}	1.7	2		uA	Ee = 0.1mW/cm ² λ = 940nm V _r = 5V
Radiant Sensitive Area	A		1.55		mm ²	
Absolute Spectral Sensitivity	S		0.6		A/W	Ee= 1mW/cm ² λ = 940nm V _r = 5V
Viewing Angle	2θ _{1/2}		140		Deg	
Wavelength of Peak sensitivity	λ _{PK}		900		nm	
Spectral BandWidth	Δλ	700	900	1100	nm	
Rise Time	t _r		50		ns	V _R = 10V λ = 940nm R _L = 1K Ω
Fall Time	t _f		50		ns	V _R = 10V λ = 940nm R _L = 1K Ω

Typical Electrical/Optical Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise indicated)

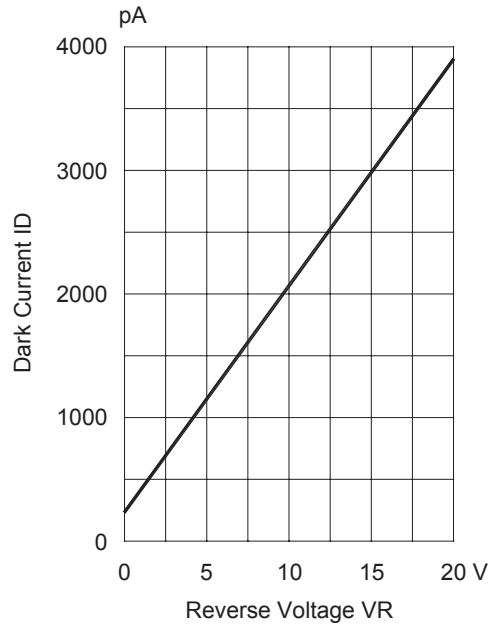


Figure 1. Dark Current Versus Reverse Voltage

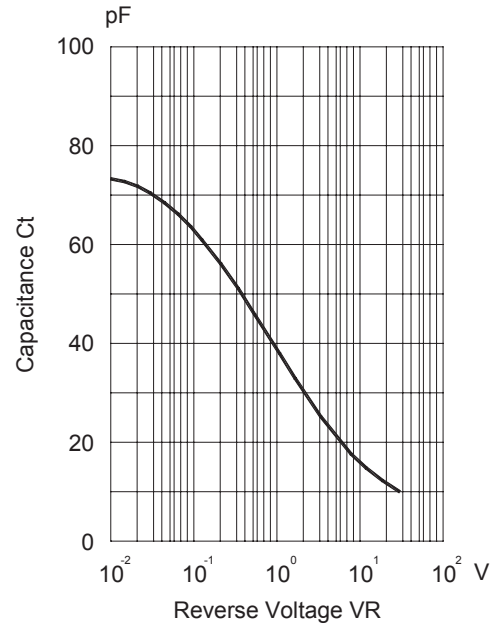


Figure 2. Capacitance Versus Reverse Voltage

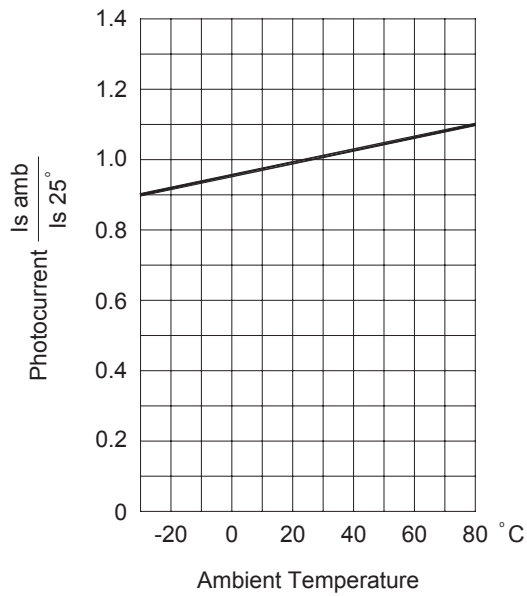


Figure 3. Photocurrent Versus Ambient Temperature

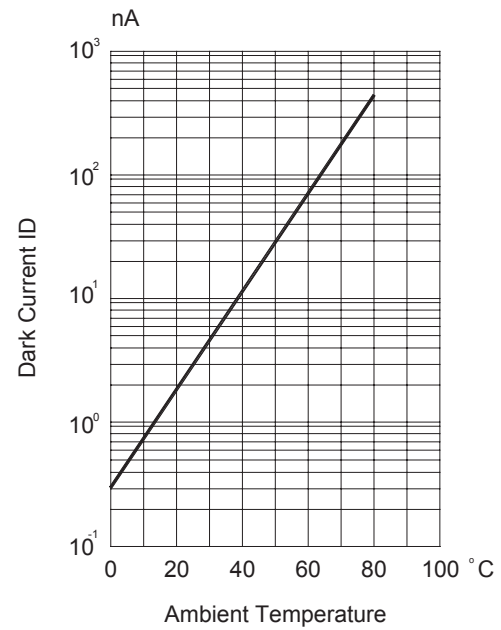


Figure 4. Dark Current Versus Ambient Temperature

Typical Electrical/Optical Characteristics Curves ($T_A=25^\circ\text{C}$ unless otherwise indicated) Cont.

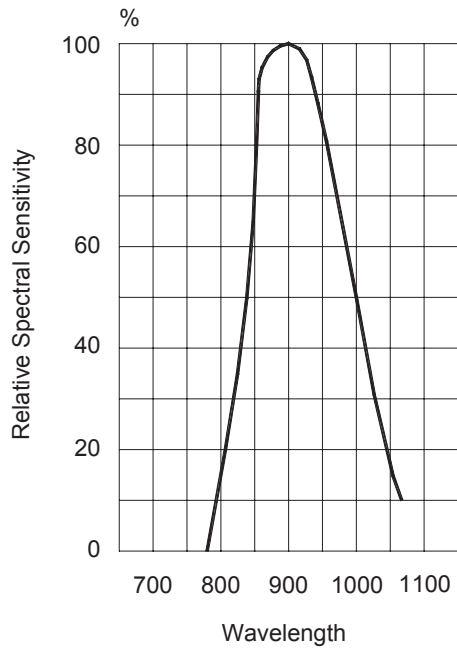


Figure 5. Relative Spectral Sensitivity Versus Wavelength

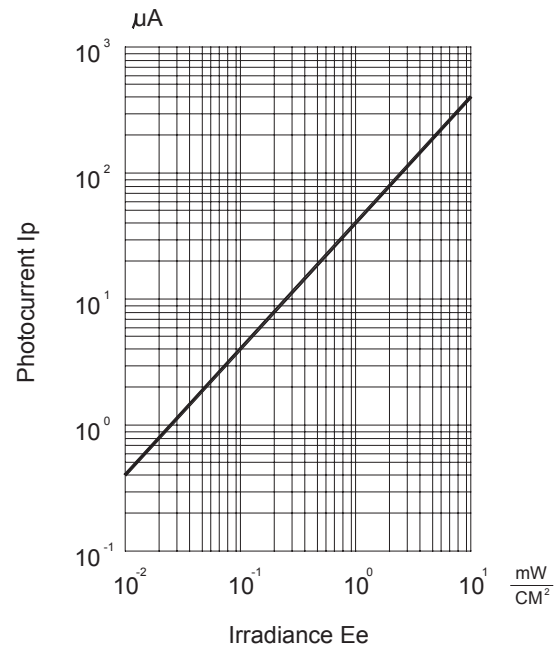


Figure 6. Photocurrent Versus Irradiance

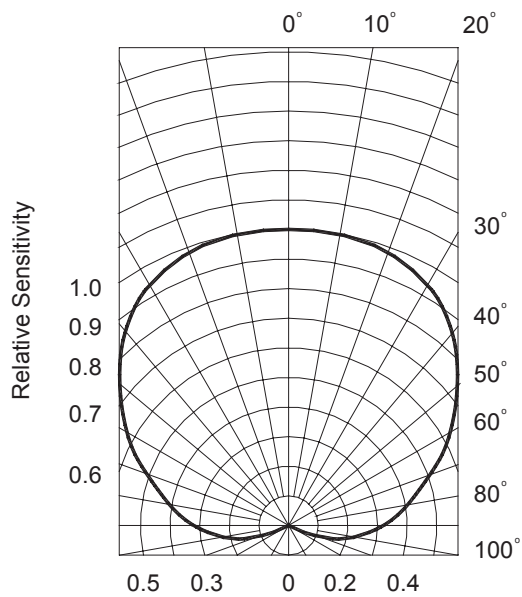


Figure 7. Sensitivity Diagram

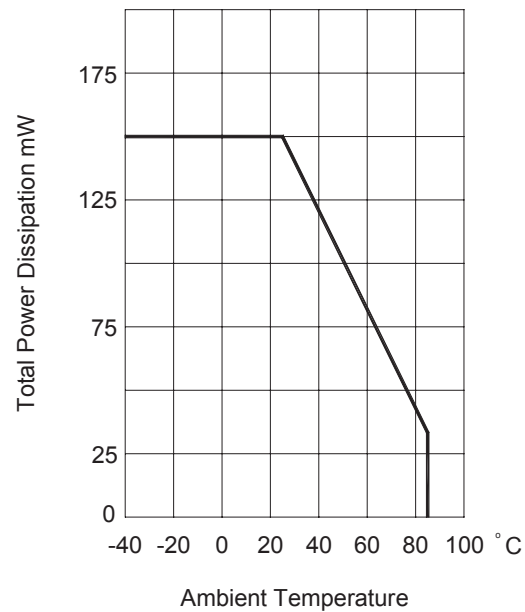


Figure 8. Total Power Dissipation Versus Ambient Temperature

For product information and a complete list of distributors, please go to our web site: www.avagotech.com